Electronic properties of Graphene and 2-D materials



- 2D materials background Carbon allotropes Graphene Structure and Band structur Electronic properties
 Electrons in a magnetic field
 - Onsager relation
 - Landau levels Quantum Hall effect
- Engineering electronic properties Kondo effect Atomic collapse and artificial atom Twisted graphene

Eva Y. Andrei

Rutgers University

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Graphene: a theorists invention

PHYSICAL REVIEW

VOLUME 71, NUMBER 9

MAY 1, 1947

The Band Theory of Graphite

P. R. WALLACE* National Research Council of Canada, Chalk River Laboratory, Chalk River, Ontario (Received December 19, 1946)

The structure of the electronic energy bands and Brillouin zones for graphite is developed using the "tight binding" approximation. Graphite is found to be a semi-conductor with zero activation energy, i.e., there are no free electrons at zero temperature, but they are created at higher temperatures by excitation to a band contiguous to the highest one which is normally filled. The electrical conductivity is treated with assumptions about the mean free path. It is found to be about 100 times as great parallel to as across crystal planes. A large and anisotropic diamagnetic susceptibility is predicted for the conduction electrons; this is greatest for fields across the layers. The volume optical absorption is accounted for.

PHYSICAL REVIEW

VOLUME 109, NUMBER 2

JANUARY 15, 1



No long range order in 2-Dimensions



...continuous symmetries cannot be spontaneously broken at finite temperature in systems with sufficiently short-range interactions in dimensions $D \le 2$.

No long range order in 2D

... No MagnetsNo superfluids ...No superconductors

No 2D crystals



First 2D materials





Graphene, hBN, MoS_2 , NbSe₂, Bi₂Sr₂CaCu₂O_x,

Two-dimensional atomic crystals

K. S. Novoselov*, D. Jiang*, F. Schedin*, T. J. Booth*, V. V. Khotkevich*, S. V. Morozov[†], and A. K. Geim*[‡]

*Centre for Mesoscience and Nanotechnology and School of Physics and Astronomy, University of Manchester, Manchester M13 9PL, United Kingdom; and [†]Institute for Microelectronics Technology, Chernogolovka 142432, Russia

Edited by T. Maurice Rice, Swiss Federal Institute of Technology, Zurich, Switzerland, and approved June 7, 2005 (received for review April 6, 2005)

We report free-standing atomic crystals that are strictly 2D and can be viewed as individual atomic planes pulled out of bulk crystals or as unrolled single-wall nanotubes. By using micromechanical cleavage, we have prepared and studied a variety of 2D crystals including single layers of boron nitride, graphite, several dichalcogenides, and complex oxides. These atomically thin sheets (essentially gigantic 2D molecules unprotected from the immediate environment) are stable under ambient conditions, exhibit high crystal quality, and are continuous on a macroscopic scale. wafer (Fig. 1*d*), because even a monolayer adds up sufficiently to the optical path of reflected light so that the interference color changes with respect to the one of an empty substrate (phase contrast). The whole procedure takes literally half an hour to implement and identify probable 2D crystallites. Their further analysis was done by atomic force microscopy (AFM), for which single-layer crystals were selected as those exhibiting an apparent (12) thickness of approximately the interlayer distance in the corresponding 3D crystals.



Can We Cheat Nature?

ANY LAYERED MATERIAL

SLICE DOWN TO ONE ATOMIC PLANE?



A. Geim

Making graphene

P. Blake et.al, 2007 D. S. L. Abergel 2007 S. Roddaro et. al Nano Letters 2007

Novoselev et al (2005)





Properties: Mechanical

Unsupported graphene with Cu particles



Young's modulus E ~ 2TPa Stiffest materal



T. Booth et al, Nano Letters'08

• Young's modulus ~ 2 TPa





Properties: Optical



Transmittance at Dirac point:

 $T=1-\alpha\pi = 97.2\%$

R.R. Nair et al, Science (2008).



P. Blake et al, Nano Letters, '08



Properties: Chemical

Single molecule detection



F Schedin et al, Nature Materials '07



2D Building Blocks



E.g.: Graphene, hBN, Silicene, Germanene, Stanene.

- About 40 2D materials are currently known.
- About half of them have been isolated.
- Others shown to be stable using simulations.

Transition Metal Dichalcogenides (TMDCs)



 $\mathsf{E.g.:}\ \mathsf{MoS}_2\ \mathsf{,WSe}_2\ \mathsf{,}\ \mathsf{NbS}_2\mathsf{,}\ \mathsf{TaS}_2$



Group 13 Monochalcogenides



E.g.: GaS, InSe



10



Van der Waals heterostructures







Nature 499, 419 (2013)

Stacking 2D Layers





The most important element in nature

Periodic Table of the Elements



Carbon chemical bonds



Carbon chemical bonds



Carbon chemical bonds



Carbon allotropes



Diamond is Metastable in ambient conditions!!



Carbon Allotropes

sp²



Graphite ~16 centur





Graphene Single -layer 2005 "1D"



Carbon nanotube Multi-wall1991 Single wall 1993 1996 "0D"



Buckyball 1985





 2D materials – background
Carbon allotropes
Graphene Structure and Band structure
Electronic properties
 Electrons in a magnetic field
Onsager relation
Landau levels
Quantum Hall effect
Engineering electronic properties
Kondo effect
Atomic collapse and artificial atom
Twisted graphene



Tight binding model



Eigenstates of the isolated atom:

$$H_{at} | \varphi_{\alpha} \rangle = E_{\alpha} | \varphi_{\alpha} \rangle$$

Overlaps between orbitals → corrections to system Hamiltoniar

$$H(r) = \sum_{R} H_{at}(r - R) + \Delta U(r - R)$$

$$H|\psi_k\rangle = E_k|\psi_k\rangle$$

• Tight binding \mapsto small overlaps \mapsto small corrections ΔU



Tight binding model

Build Bloch waves out of atomic orbitals (Bravais lattice!)

$$|\psi_{k\alpha}(\mathbf{r})\rangle = \sum_{\mathbf{R}_{j}} e^{ik \cdot \mathbf{R}_{j}} |\varphi_{\alpha}(\mathbf{r} - \mathbf{R}_{j})\rangle$$
 Lattice vector

Solutions have to satisfy:

1. Normalization

$$\left\langle \boldsymbol{\psi}_{k}\left|\boldsymbol{\psi}_{k}\right\rangle =1$$

2. Eigenstate of the Hamiltonian

$$\left\langle \boldsymbol{\psi}_{k} \left| \boldsymbol{H} \right| \boldsymbol{\psi}_{k} \right\rangle = E_{k}$$

- 3. Algebra \mapsto Find Solutions in terms of:
- Nearest neighbor transfer (hopping) integral
- Nearest neighbour overlap integral

$$H = \sum_{\langle i,j \rangle} t_{ij} c_i^{\dagger} c_j + h.c.$$





Band Structure





↑Ε

Simple metal



Bravais latticeParabolic dispersion

$$E = \frac{p^2}{2m^*}$$



How is graphene different?



Wallace, 1947

honeycomb lattice Not Bravais
strong diffraction by lattice

unconventional dispersion





Graphene honeycomb lattice

1. 2D

- 2. Honeycomb structure (non-Bravais)
- 3. 2 identical atoms/cell



2 interpenetrating Bravais (triangular) lattices



Honeycomb lattice - two sets of Bloch functions

1. 2D

- 2. Honeycomb structure (non-Bravais)
- 3. 2 identical atoms/cell



B

$$\Phi_B\left(\vec{k}, \vec{r}\right) = \frac{1}{\sqrt{N}} \sum_{\vec{k}_B}^{N} e^{i\vec{k}\cdot\vec{R}_B} \varphi_B\left(\vec{r} - \vec{R}_B\right)$$

sum over all type B atomic sites in N unit cells

atomic wavefunction





Honeycomb lattice - two sets of Bloch functions



New degree of freedom –like spin up and spin down - but instead sublattice A or $B \mapsto pseudo-spin$



Tight binding model of monolayer graphene : Energy solutions

$$H = \begin{pmatrix} \varepsilon_B & -tf(\vec{k}) \\ -tf^*(\vec{k}) & \varepsilon_B \end{pmatrix}; \quad S = \begin{pmatrix} 1 & sf(\vec{k}) \\ sf^*(\vec{k}) & 1 \end{pmatrix}$$



$$\varepsilon_{A} \equiv \langle \varphi_{A} | H | \varphi_{A} \rangle; \varepsilon_{B} = \langle \varphi_{B} | H | \varphi_{B} \rangle$$

$$t \equiv \langle \varphi_{A} | H | \varphi_{B} \rangle$$

identical atoms : $\varepsilon_0 = \varepsilon_A = \varepsilon_B$

Edward McCann arXiv:1205.4849

 $f(\vec{k}) = \sum_{\vec{s}=1}^{3} e^{i\vec{k}\cdot\vec{\delta}_{j}} = e^{ik_{y}a/\sqrt{3}} + 2e^{-ik_{y}a/2\sqrt{3}}\cos\left(\frac{k_{x}a}{2}\right)$

Secular equation gives the eigenvalues:

$$\det(H-ES)=0$$

$$\det \begin{pmatrix} \varepsilon_0 - E & -(t + Es)f(\vec{k}) \\ -(t + Es)f^*(\vec{k}) & \varepsilon_0 - E \end{pmatrix} = 0$$
$$(E - \varepsilon_0)^2 - (t + Es)^2 \left| f(\vec{k}) \right|^2 = 0$$

$$E = \frac{\varepsilon_0 \pm t \left| f\left(\vec{k}\right) \right|}{1 \mp s \left| f\left(\vec{k}\right) \right|}$$

Note: If atoms on the two sublattices are different:

$$H = \begin{pmatrix} \varepsilon_A & -tf(\vec{k}) \\ -tf^*(\vec{k}) & \varepsilon_B \end{pmatrix}$$

Solutions more complicated

Graphene tight binding band structure



$$f\left(\vec{k}\right) = e^{ik_y a/\sqrt{3}} + 2e^{-ik_y a/2\sqrt{3}} \cos\left(\frac{k_x a}{2}\right)$$

Typical parameter values :

$$\varepsilon_0 = 0, t = 3.033 eV, s = 0.129$$







Band Structure

$$\psi_{\vec{k}}(\vec{r}) = c_A | \langle Q_A \rangle + c_B | \langle Q_B \rangle = \begin{pmatrix} \psi_{\uparrow} \\ \psi_{\downarrow} \end{pmatrix}$$

New degree of Freedom Pseudospin



Low energy excitations

Dirac cones



Dirac point

6 Dirac points, but only 2 independent points K and K', others can be derived with translation by reciprocal lattice vectors.

The Dirac points are protected by 3 discrete symmetries: T, I, C_3











<u>1 Linear expansion near the K point</u>



$$H = \begin{pmatrix} 0 & -tf(\vec{k}) \\ -tf^*(\vec{k}) & 0 \end{pmatrix} \approx v_F \begin{pmatrix} 0 & \xi p_x - ip_y \\ \xi p_x + ip_y & 0 \end{pmatrix} \qquad v_F = \frac{\sqrt{3}at}{2\hbar} \approx 10^6 \, m/s$$



2. Dirac-like equation with Pseudospin

For one K point (e.g. $\xi = +1$) we have a 2 component wave function,

$$\boldsymbol{\psi} = \begin{pmatrix} \boldsymbol{\psi}_A \\ \boldsymbol{\psi}_B \end{pmatrix}$$

with the following effective Hamiltonian (Dirac Weyl Hamiltonian):

$$H = v_F \begin{pmatrix} 0 & p_x - ip_y \\ p_x + ip_y & 0 \end{pmatrix} = v_F (\sigma_x p_x + \sigma_y p_y) = v_F \vec{\sigma} \cdot \vec{p}$$

$$\sigma_x = :\begin{pmatrix} 0 & 1 \\ 1 & 0 \end{pmatrix}; \sigma_y = \begin{pmatrix} 0 & -i \\ i & 0 \end{pmatrix}; \sigma_z = \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix}$$

Bloch function amplitudes on the AB sites ('pseudospin') mimic spin components of a relativistic Dirac fermion.

Pauli Matrices> Operate on sublattice degree of freedom



2. Dirac-like equation with Pseudospin

To take into account both K points (ξ =+1 and ξ =-1) we can use a 4 component wave function.

$$\psi = \begin{pmatrix} \psi_{AK} \\ \psi_{BK} \\ \psi_{AK'} \\ \psi_{BK'} \end{pmatrix}$$

Note: real spin not included. Including spin gives 8x8 Hamiltonian

with the following effective Hamiltonian:

$$H = v_{F} \begin{pmatrix} 0 & p_{x} - ip_{y} & 0 & 0 \\ p_{x} + ip_{y} & 0 & 0 \\ 0 & 0 & 0 \\ 0 & 0 & -p_{x} - ip_{y} \\ 0 & 0 & -p_{x} + ip_{y} & 0 \end{pmatrix}$$

$$H_{K} = v_{F}\vec{\sigma}.\vec{p}$$
 $H_{K'} = -v_{F}\vec{\sigma}^{*}.\vec{p}$
H_K and H_{K'} are related by time reversal symmetry

Massless Dirac fermions

<u>3. Massless Dirac Fermions</u> Hamiltonian near K point:

$$H = \hbar v_F \begin{pmatrix} 0 & -i\partial_x + \partial_y \\ -i\partial_x - \partial_y & 0 \end{pmatrix} = \hbar v_F \left(-i\sigma_x \partial_x - i\sigma_y \partial_y \right)$$

 $\varphi = \arctan(p_y / p_x) \text{ polar angle}$ s = band index

 $E = sv_F p \quad \Leftrightarrow \quad \psi = \frac{1}{\sqrt{2}} e^{i\vec{k}\cdot\vec{r}}$



Pseudospin vector

- Is parallel to the wave vector k in upper band
- Antiparallel to k in lower band (s=-1)

Massless particle : m=0
..Photons, neutrinos..
$$E = cp$$
> But 300 times slower
$$v_F \approx 10^6 m/s$$



No backscattering within Dirac cone

4. Absence of backscattering within a Dirac cone

$$\psi = \frac{1}{\sqrt{2}} e^{i\vec{\mathbf{k}}\cdot\vec{\mathbf{r}}} \begin{pmatrix} 1\\ se^{i\varphi} \end{pmatrix}$$

angular scattering probability:



$$\langle \psi(\varphi) | \psi(\varphi=0) \rangle |^2 = \cos^2(\varphi/2)$$

under pseudospin conservation, backscattering within one valley is suppressed



Helicity (Chirality)

5. Helicity Hamiltonian at K point:

$$H(K) = v_F \vec{\sigma} \cdot \vec{p} = v_F p \vec{\sigma} \cdot \vec{n}$$

Helicity operator: $\hat{h} = \vec{\sigma} \cdot \vec{n}$

$$H(K) = v_F p \hat{h}$$

Helicity is conserved

Helical electrons pseudospin direction is linked to an axis determined by electronic momentum.

for conduction band electrons, $\vec{\sigma} \cdot \vec{n} = 1$

 $\vec{\sigma} \cdot \vec{n} = -1$ valence band ('holes')



Helicity (Chirality)

5. Helicity



Helical electrons pseudospin direction is linked to an axis determined by electronic momentum.

for conduction band electrons, $\vec{\sigma} \cdot \vec{n} = 1$

 $\vec{\sigma} \cdot \vec{n} = -1$ valence band ('holes')

E.Y. Andrei

Helicity conserved \mapsto No backscattering between cones



No Backscattering





Pristine graphene

 $Pseudospin + chirality \mapsto Klein tunneling$



No electrostatic confinement



- No switching
- No guiding



Klein tunneling



Klein "paradox"
➢ Transmission of relativistic particles
unimpeded even by highest barriers
➢ Physical picture: particle/hole conversion

Angular dependence of transmission

Katsnelson et al Nature physics (2006)



Carrier density outside the barrier is $0.5 \times 10^{12} \text{ cm}^{-2}$. Inside the barrier, hole concentrationn is 1×10^{12} and $3 \times 10^{12} \text{ cm}^{-2}$ for the red and blue curves.



The Berry phase



Proc. R. Soc. Lond. A **392**, 45–57 (1984) Printed in Great Britain

Quantal phase factors accompanying adiabatic changes



BY M. V. BERRY, F.R.S.

Imagine a quantal sy changing environment ment, and hence \hat{H} , is s 1962) that at any insta In particular, if the H return to its original st by interference if the from it at an earlier ti

My purpose here is component $\exp(i\gamma)$ in which accompanies th in terms of the eigens degeneracy in the spederived in §3; this cor of the eigenstates of



effects of an unate. If the environtheorem (Messiah is instantaneous \hat{H} . im the system will factor is observable that was separated stant.

circuit-dependent ment exp ($-iEt/\hbar$) eral formula for γ circuit is close to a form which will be bund a degeneracy well as Hermitian



Berry phase



Examples





- Curved space
- Mobius strip
- Twisted optical fiber
- Bohm Aharonov phase
- Dirac belt



Berry Phase Tutorial: https://www.physics.rutgers.edu/grad/682/textbook/ch-3.pdf

Berry phase





Berry phase = $-\operatorname{Im} \oint_{\lambda} d\lambda \left[\psi_{\lambda} \frac{d\psi_{\lambda}}{d\lambda} \right] = \pi$ Home Prove

Homework: Prove this relationship



Graphene Relatives

- Many natural materials have Dirac cones in their bandstructure (e.g. highTc compnds). But the Fermi surface of these materials contains many states that are not on a Dirac cone. As a result the electronic properties are controlled by the normal electrons and the Dirac electrons are invisible.
- Graphene is the ONLY naturally occurring material where the Fermi surface consists of Dirac points alone. As a result all its electronic properties are controlled by the Dirac electrons.





Graphene - bfifisktootsture

Ingredients



2D
 Honeycomb structure

3. 2 identical atoms/cell





Graphene (2005) Silicene (2010) *Germanine (2014)* Stanene (2013)

Phosphorene (2014) Borophene B₃₆ (2014)



Artificial Graphene



Ingredients:

- 1. 2D
- 2. Honeycomb structure
- 3. Identical populations

LETTER

doi:10.1038/nature10941

Designer Dirac fermions and topological phases in molecular graphene

Kenjiro K. Gomes^{1,2}*, Warren Mar^{2,3}*, Wonhee Ko^{2,4}*, Francisco Guinea⁵ & Hari C. Manoharan^{1,2}



 $a \sim 2nm$

 $t \propto \frac{\hbar^2}{m^* a^2} \approx 120 meV$ $v_F = t \frac{3a}{2\hbar} \approx 3 \times 10^5 \, m/s$









Graphene bandstructure



1. 2D

- 2. Honeycomb structure
- 3. 2 identical atoms/cell
- 4. $t_1 = t_2 = t_3 = t$



Can one control/manipulate the bandstructure?

> Relax the condition: $t_1 = t_2 = t_3$

- ✓ Strain
- ✓ Impose external potential
- ✓ Hybridization
- Electrostatic potential
- Defects





- 1. 2D
- 2. Honeycomb structure (non-Bravais)
- 3. 2 identical atoms/cell

$$H = v_F \vec{\sigma}.\vec{p}$$

$$E = sv_F p \quad ; \quad \psi = \frac{1}{\sqrt{2}} e^{i\vec{k}\cdot\vec{r}} \begin{pmatrix} 1\\ se^{i\varphi} \end{pmatrix}$$

- $s = \pm 1$ band index
- Pseudospin ; Helicity
- Chiral quasiparticles
- No backscattering

Berry phase π

Density of states

$$g(E) = 2 \frac{L^2}{\pi (\hbar v_F)^2} |E|$$

1



